MPX4250D

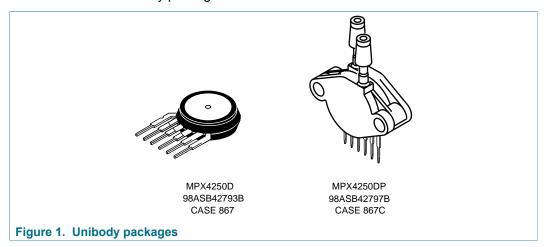
0 to 250 kPa, Differential, gauge pressure sensor, on-chip signal conditioned, temperature compensated and calibrated Rev. 8.0 — 25 July 2017 Data sheet: technical data

1 General description

The MPX4250D series piezoresistive transducer is a state-of-the-art monolithic silicon pressure sensor designed for a wide range of applications, particularly those employing a microcontroller or microprocessor with A/D inputs. This transducer combines advanced micromachining techniques, thin-film metallization, and bipolar processing to provide an accurate, high-level analog output signal that is proportional to the applied pressure. The small form factor and high reliability of on-chip integration make the NXP sensor a logical and economical choice for the automotive system engineer.

2 Features

- · Differential and gauge applications available
- 1.4 % maximum error over 0 °C to 85 °C
- · Patented silicon shear stress strain gauge
- Temperature compensated over -40 °C to +125 °C
- · Offers reduction in weight and volume compared to existing hybrid modules
- Durable epoxy unibody element
- · Available in two unibody packages



3 Typical applications

· Ideally suited for microprocessor or microcontroller-based systems



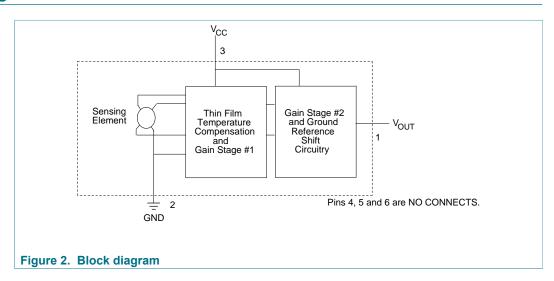
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4 Ordering information

Table 1. Ordering information

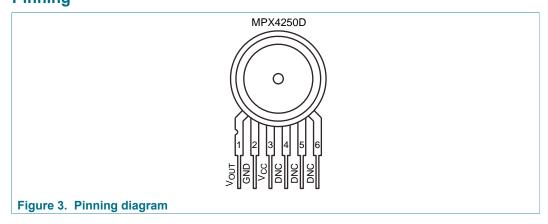
Device name	Package	Package	# of Ports Pressure type)	Device		
Device name	Options	Options Name	None	Single	Dual	Gauge	Differential	Absolute	marking
MPX4250D	Tray	98ASB42793B	•				•		MPX4250D
MPX4250DP	Tray	98ASB42797B			•		•		MPX4250DP

5 Block diagram



6 Pinning information

6.1 Pinning



0 to 250 kPa, Differential, gauge pressure sensor, on-chip signal conditioned, temperature compensated and calibrated

6.2 Pin description

Table 2. Pin descriptions

Symbol	Pin	Description
V _{OUT}	1	Output voltage
GND	2	Ground
V _{CC}	3	Voltage supply
DNC	4	Do not connect to external circuitry or ground
DNC	5	Do not connect to external circuitry or ground
DNC	6	Do not connect to external circuitry or ground

7 Mechanical and electrical specifications

7.1 Maximum ratings

Table 3. Maximum ratings

Exposure beyond the specified limits may cause permanent damage or degradation to the device.

Rating	Symbol	Value	Unit
Maximum pressure (P1 > P2)	P_{MAX}	1000	kPa
Storage temperature	T _{STG}	-40 to +125	°C
Operating temperature	T_A	-40 to +125	°C

<u>Figure 2</u> shows a block diagram of the internal circuitry integrated on a pressure sensor chip.

7.2 Operating characteristics

Table 4. Operating characteristics

 $(V_{CC} = 5.1 \text{ Vdc}, T_A = 25 \text{ °C unless otherwise noted}, P1 > P2. Decoupling circuit shown in Figure 5 required to meet electrical specifications.)$

Symbol	Characteristic	Min	Тур	Max	Unit
P _{OP}	Pressure range ^[1]	0	_	250	kPa
V _{CC}	Supply voltage ^[2]	4.85	5.1	5.35	Vdc
Io	Supply current	_	7.0	10	mAdc
$V_{\rm off}$	Minimum pressure offset ^[3] (0 °C to 85 °C)	0.139	0.204	0.269	Vdc
V_{FSO}	Full scale output ^[4] (0 °C to 85 °C)	4.844	4.909	4.974	Vdc
V_{FSS}	Full scale span ^[5] (0 °C to 85 °C)	_	4.705	_	Vdc
	Accuracy ^[6] (0 °C to 85 °C)	_		±1.4	%V _{FSS}
ΔV/ΔΡ	Sensitivity		18.8		mV/kPa
t _R	Response time ^[7]	_	1.0		ms
l _{o+}	Output source current at full scale output	_	0.1	<u></u> -	mAdc

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Symbol	Characteristic	Min	Тур	Max	Unit
_	Warm-up time ^[8]	_	20		ms
_	Offset stability ^[9]	_	±0.5		%V _{FSS}

- [1] 1.0 kPa (kiloPascal) equals 0.145 psi.
- [2] Device is ratiometric within this specified excitation range.
- Offset (V_{off}) is defined as the output voltage at the minimum rated pressure.
- 4] Full scale output (V_{FSO}) is defined as the output voltage at the maximum or full rated pressure.
- 5] Full scale span (V_{FSS}) is defined as the algebraic difference between the output voltage at full rated pressure and the output voltage at the minimum rated pressure.
- [6] Accuracy (error budget) consists of the following:
 - · Linearity: Output deviation from a straight line relationship with pressure over the specified pressure range.
 - Temperature hysteresis: Output deviation at any temperature within the operating temperature range, after the temperature is cycled to and from the minimum or maximum operating temperature points, with zero pressure applied.
 - Pressure hysteresis: Output deviation at any pressure within the specified range, when this pressure is cycled to and from the minimum or maximum rated pressure, at 25 °C.
 - TcSpan: Output deviation over the temperature range of 0 °C to 85 °C, relative to 25 °C.
 - TcOffset: Output deviation with minimum rated pressure applied, over the temperature range of 0 °C to 85 °C, relative to 25 °C.
 - Variation from nominal: The variation from nominal values, for offset or full scale span, as a percent of V_{FSS}, at 25 °C.
- [7] Response time is defined as the time for the incremental change in the output to go from 10 % to 90 % of its final value when subjected to a specified step change in pressure.
- [8] Warm-up time is defined as the time required for the product to meet the specified output voltage after the pressure has been stabilized.
- [9] Offset stability is the product's output deviation when subjected to 1000 hours of pulsed pressure, temperature cycling with bias test.

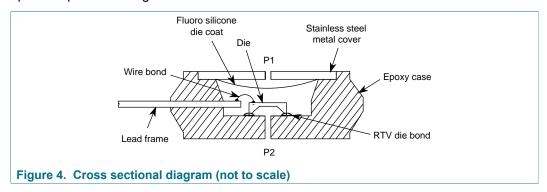
8 On-chip temperature compensation and calibration

<u>Figure 4</u> illustrates the differential/gauge pressure sensing chip in the basic chip carrier (98ASB42793B). A fluorosilicone gel isolates the die surface and wire bonds from the environment, while allowing the pressure signal to be transmitted to the sensor diaphragm.

The MPX4250D series pressure sensor operating characteristics and internal reliability and qualification tests are based on use of dry air as the pressure media. Media, other than dry air, may have adverse effects on sensor performance and long-term reliability. Contact the factory for information regarding media compatibility in your application.

<u>Figure 5</u> shows the recommended decoupling circuit for interfacing the output of the integrated sensor to the A/D input of a microprocessor or microcontroller.

<u>Figure 6</u> shows the sensor output signal relative to pressure input. Typical, minimum, and maximum output curves are shown for operation over a temperature range of 0 °C to 85 °C using the decoupling circuit shown in <u>Figure 5</u>. The output will saturate outside of the specified pressure range.



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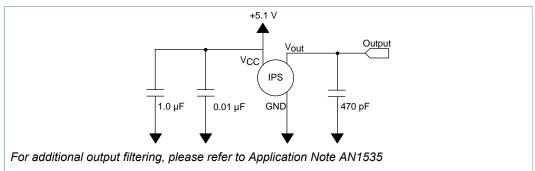
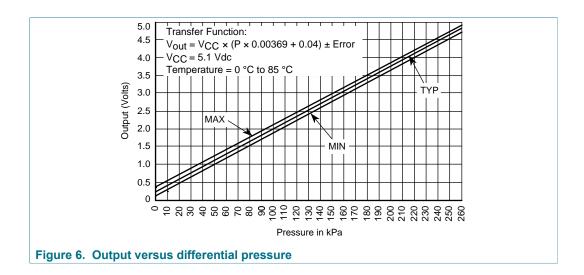


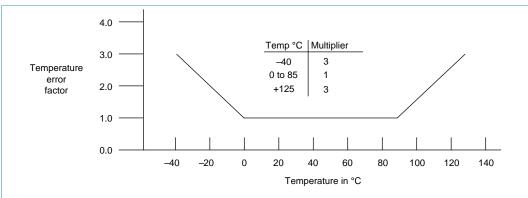
Figure 5. Recommended power supply decoupling and output filtering



 $V_{OUT} = V_{CC} \times (P \times 0.00369 + 0.04) \pm (Pressure Error \times Temp. Factor \times 0.00369 \times V_{CC})$ Nominal transfer value:

 $V_{CC} = 5.1 \pm 0.25 \text{ Vdc}$

Figure 7. Transfer function

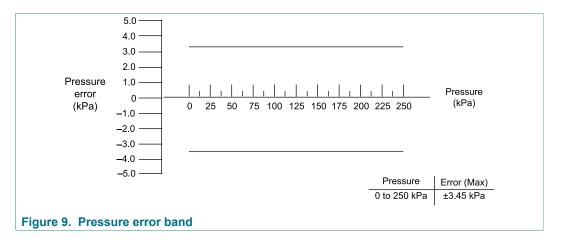


Note: The temperature multiplier is a linear response from 0°C to -40°C and from 85°C to 125°C.

Figure 8. Temperature error band

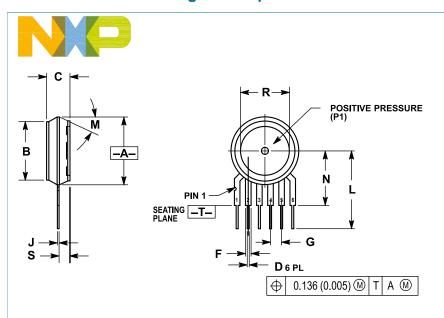
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Package information

Package description



- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

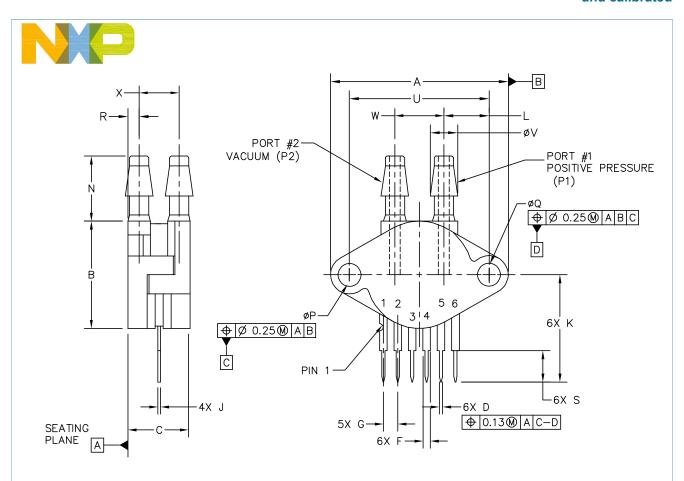
 2. CONTROLLING DIMENSION: INCH.

 3. DIMENSION -A- IS INCLUSIVE OF THE MOLD STOP RING, MOLD STOP RING NOT TO EXCEED 16.00 (0.630).

	INC	HES	MILLIN	IETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.595	0.630	15.11	16.00	
В	0.514	0.534	13.06	13.56	
С	0.200	0.220	5.08	5.59	
D	0.027	0.033	0.68	0.84	
F	0.048	0.064	1.22	1.63	
G	0.100	BSC	2.54 BSC		
J	0.014	0.016	0.36	0.40	
L	0.695	0.725	17.65	18.42	
M	30°	NOM	30°NOM		
N	0.475	0.495	12.07	12.57	
R	0.430	0.450	10.92	11.43	
S	0.090	0 105	2 29	2 66	

Figure 10. Package name 98ASB42793B, Case 867-08, Issue N

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DIM	MILLIM MIN	ETERS MAX	DIM	MILLIM MIN	ETERS MAX	NOTES:	
А	29.08	29.85	Р	ø3.89	ø4.04	1. DIME	NSIONS ARE IN MILLIMETERS.
В	17.40	18.16	Q	ø3.89	ø4.04	2. DIME	ENSIONS AND TOLERANCES PER
С	10.29	11.05	R	1.60	2.11	ASN	ME Y14.5M-1994.
D	0.68	0.84	S	5.59	6.10	3. 867C-01 THRU -04 OBSOLATE, NEV STANDARD 867C-05.	
F	1.22	1.63	U	23.11	BSC		
G	2.54	BSC	v	4.62	4.93		
J	0.36	0.41	w	7.87	8.38		
K	17.65	18.42	x	6.30	7.06		
L	7.37	7.62					
N	10.67	11.18					
(NDUCTORS N.V. IS RESERVED		MECHA	NICAL OU	TLINE	PRINT VERSION NOT TO SCALE
TITLE	:					DOCUME	NT NO: 98ASB42797B REV: H
	SENSOR, 4 LEAD UNIBODY			STANDAF	RD: NON-JEDEC		
			SOT1756	-1 29 JAN 2016			

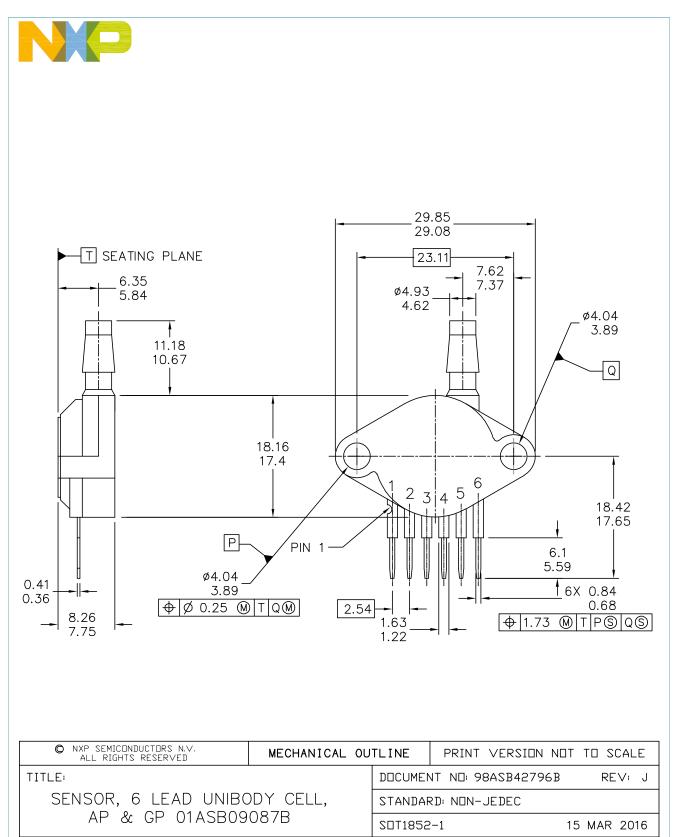
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Figure 11. Package name 98ASB42797B, Case 867C-05, Issue H

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NOTES:

- 1. DIMENSIONS ARE IN MILLIMETERS.
- 2. DIMENSIONS AND TOLERANCES PER ASME Y14.5M-1994.
- 3. 867B-01 THRU -3 OBSOLETE, NEW STANDARD 867B-04.

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TITLE:			NT NO: 98ASB42796B	REV: J
SENSOR, 6 LEAD UNIBO	STANDAR	RD: NON-JEDEC		
AP & GP 01ASB09087B		S0T1852	2–1 1	5 MAR 2016

Figure 12. Package name 98ASB42796B, Case 867B-04, Issue J

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10 Revision history

Table 5. Revision history

Document ID	Release date	Data sheet status	Change notice	Supercedes
MPX4250D v.8.0	20170725	Technical data	_	MPX4250 v.7.0
Modifications:	The format of this data NXP Semiconductors. Legal texts have been Revised "MPX4250" to Updated the documen Pressure Sensor On-C "20 to 250 kPa, Manifo compensated and cali Added Figure 1 "Unibo Updated Table 1 "Orde Revised Figure 2 "Bloo Changed Vs to VCC Revised the note to Added pinning illustrate Added pin descriptions Changed Vs to VCC in in Section 7.2 "Operate Updated the figures in follows: Figure 4 "Cross section Figure 5 "Recomme Figure 6 "Output ver Figure 7 "Transfer for Figure 9 "Pressure 6" Updated the figures ar Figure 10 "Package Figure 11 "Package Figure 11" Package	a sheet has been redesign adapted to the new comportance of "MPX4250D." It title from "Integrated Silchip Signal Conditioned, old absolute pressure serbrated." It is section and gram in Section in S	tion 4 "Ordering informati "Block diagram" as follow NO CONNECTS" diagram" in Section 6.1 " ions" in Section 6.2 "Pin on the body of Table 4 "Operature compensation and perature compensation and perature description and output filtering of the section of	ew identity guidelines of priate. anifold Absolute ted and Calibrated" to itioned, temperature on". ws: Pinning". description". perating characteristics" and calibration" as
MPX4250 v.7.0	20090131	Technical data		MPX4250 v.6.0

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[short] Data sheet: technical data	Production	This document contains the product specification. NXP Semiconductors reserves the right to change the detail specifications as may be required to permit improvements in the design of its products.

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